FAIRCHILD

ISL9R30120G2

30 A 1200 V STEALTH™ Diode

Features

- Stealth Recovery t_{rr} = 269 ns (@ I_F = 30 A)
- Max Forward Voltage, $V_F = 3.3 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD

Package

Snubber Diode

Description

The ISL9R30120G2 is a STEALTH[™] diode optimized for low loss performance in high frequency hard switched applications. The STEALTH[™] family exhibits low reverse recovery current (I_{RR}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RR} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH[™] diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Symbol

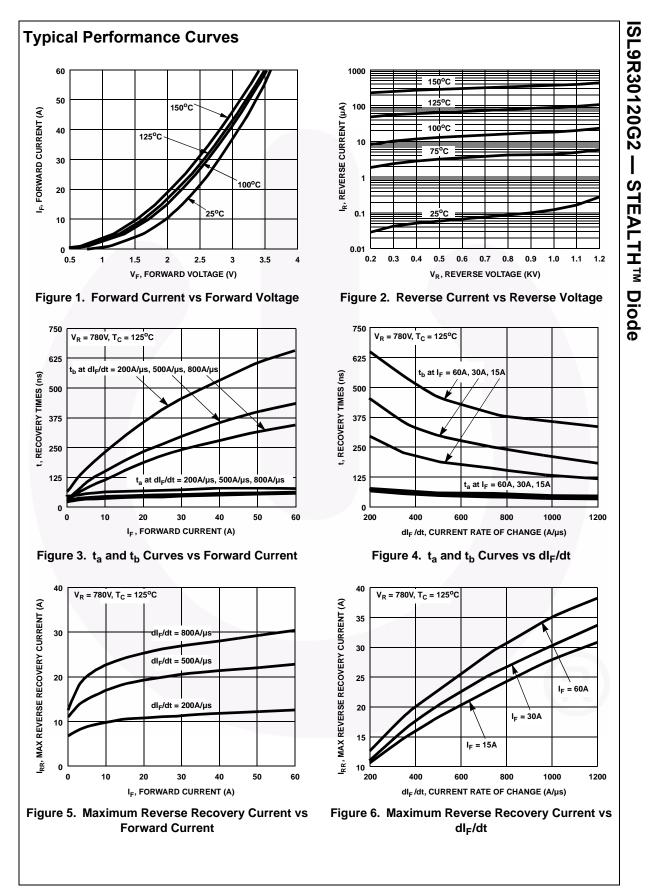
ANODE CATHODE (BOTTOM SIDE METAL) A

Device Maximum Ratings T_C = 25°C unless otherwise noted

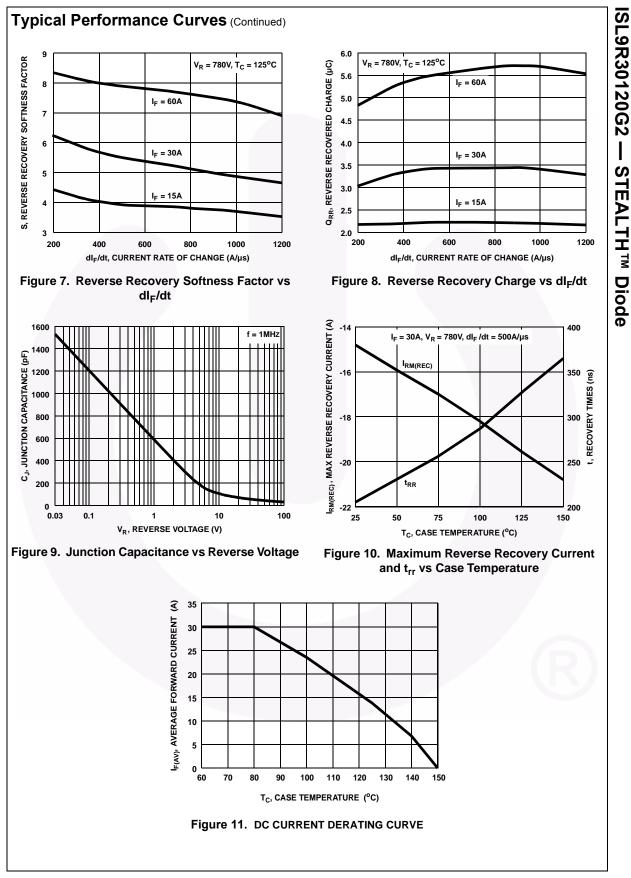
JEDEC STYLE 2 LEAD TO-247

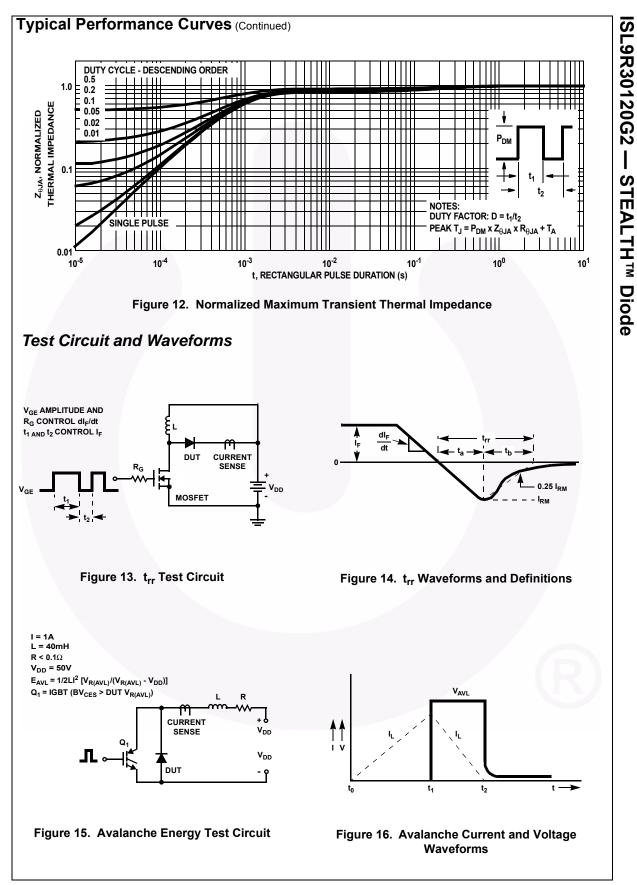
Symbol	Parameter	Rating	Unit
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V
V _{RWM}	Working Peak Reverse Voltage	1200	V
V _R	DC Blocking Voltage	1200	V
I _{F(AV)}	Average Rectified Forward Current (T _C = 80°C)	30	A
I _{FRM}	Repetitive Peak Surge Current (20 kHz Square Wave)	70	A
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	325	А
PD	Power Dissipation	166	W
E _{AVL}	Avalanche Energy (1 A, 40 mH)	20	mJ
Г _Ј , Т _{STG}	Operating and Storage Temperature Range	-55 to 150	°C
ΤL	Maximum Temperature for Soldering	300	°C
T _{PKG}	Leads at 0.063 in (1.6 mm) from Case for 10 s Package Body for 10s, See Application Note AN-7528	260	°C

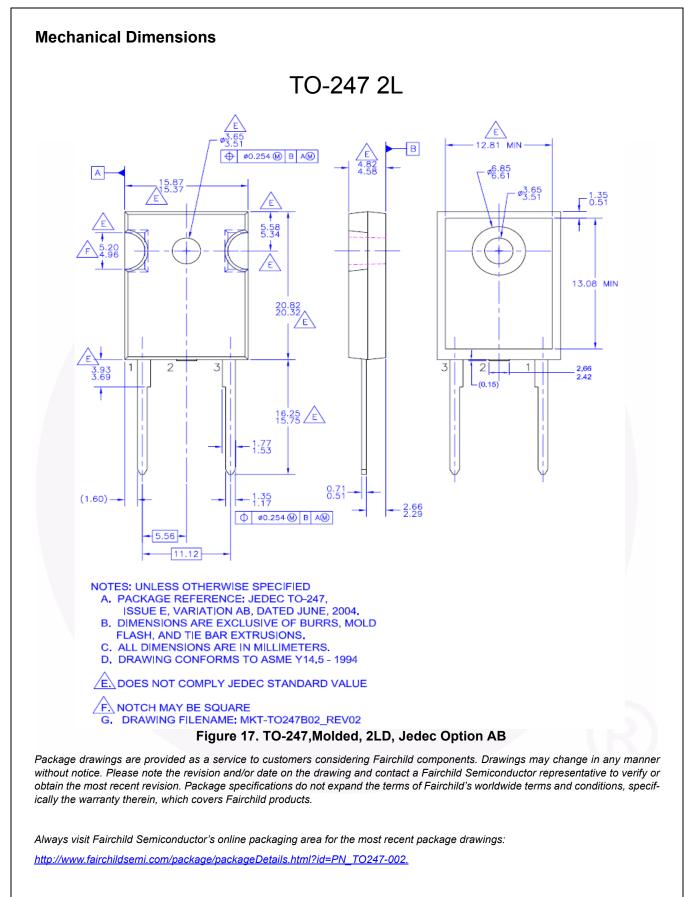
Device MarkingDeviceR30120G2ISL9R30120G2		PackagePacking MethodeTO-247Tube		Tape V	Vidth	Quan	tity		
				-	N/A		30		
lectric	cal Char	acteristics т _с = 25°С u	nless otherwi	se note	d				
Symbol		Parameter	Test Conditions		Min	Тур	Max	Unit	
ff State	e Characte	eristics							
I _R	Instantaneous Reverse Current		V _R = 1200 V		Г _С = 25°С	-	-	100	μA
					Г _С = 125°С	-	-	1.0	mA
n State	Characte	ristics							
V _F	Instantaneo	ous Forward Voltage	I _F = 30 A	ŀ	Г _С = 25°С	-	2.8	3.3	V
			-		Г _С = 125°С	-	2.6	3.1	V
vnamio	Characte	eristics							
CJ	Junction Ca		V _R = 10 V, I _F	= 0 A		-	115	· - 1	pF
			K /1	_					
	g Charact		$\begin{split} I_{F} &= 1 \text{ A, } dI/dt = 100 \text{ A/}\mu\text{s, } \text{V}_{R} = 15 \text{ V} \\ I_{F} &= 30 \text{ A, } dI/dt = 100 \text{ A/}\mu\text{s, } \text{V}_{R} = 15 \text{ V} \\ I_{F} &= 30 \text{ A, } \\ dI_{F}/dt &= 200 \text{ A/}\mu\text{s, } \\ \text{V}_{R} &= 780 \text{ V, } \text{T}_{C} = 25^{\circ}\text{C} \end{split}$			45	50		
t _{rr}	Reverse Re	covery Time			-	45 80	56 100	ns ns	
t _{rr}	Reverse Re	covery Time			-	269	-	ns	
I _{rr}		ecovery Current			_	7.5	-	A	
Q _{rr}		covered Charge			-	930	-	nC	
t _{rr}		covery Time	I _F = 30 A,			-	529	-	ns
S	Softness Fa	· · · · · · · · · · · · · · · · · · ·	dl _F /dt = 200 A/µs,		-	6.2	-	-	
I _{rr}		ecovery Current	V _R = 780 V,			-	11	-	Α
Q _{rr}	Reverse Re	covered Charge	T _C = 125°C			-	3.0	-	μC
t _{rr}	Reverse Re	covery Time	I _F = 30 A,	7		-	260	-	ns
S	Softness Fa	actor $(t_{\rm b}/t_{\rm a})$	$dI_F/dt = 1000$	A/µs,		-	4.8	-	-
۱ _{rr}		ecovery Current	V _R = 780 V,		-	30	-	Α	
Q _{rr}		covered Charge	T _C = 125°C			-	3.4	-	μC
dl _M /dt		i/dt during t _b	-		-	520	-	Α/μs	
nermal	Characte	ristics						7	
$R_{\theta JC}$	1	sistance Junction to Case	TO-247			-	-	0.75	°C/W
R_{\thetaJA}	Thermal Re	esistance Junction to Ambient	TO-247			-	-	30	°C/W



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SEMICONDUCTOR

SL9R30120G2 — STEALTH[™] Diode

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